FAIRCHILD

SEMICONDUCTOR®

October 2013

FDME820NZT N-Channel PowerTrench[®] MOSFET 20 V, 9 A, 18 m Ω

Features

- Max $r_{DS(on)}$ = 18 m Ω at V_{GS} = 4.5 V, I_D = 9 A
- Max $r_{DS(on)}$ = 24 m Ω at V_{GS} = 2.5 V, I_D = 7.5 A
- Max $r_{DS(on)}$ = 32 m Ω at V_{GS} = 1.8 V, I_D = 7 A
- Low profile: 0.55 mm maximum in the new package MicroFET 1.6x1.6 Thin
- Free from halogenated compounds and antimony oxides
- HBM ESD protection level >2.5 kV (Note3)
- RoHS Compliant

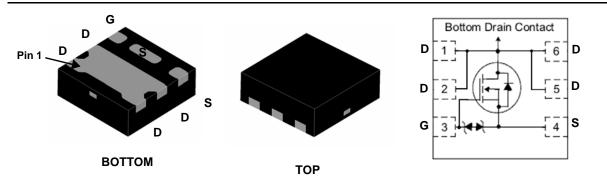


General Description

This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the $r_{DS(ON)}$ @ VGS = 1.8 V on special MicroFET leadframe.

Applications

- Li-lon Battery Pack
- Baseband Switch
- Load Switch
- DC-DC Conversion



MicroFET 1.6x1.6 Thin

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Paramet		Ratings	Units		
V _{DS}	Drain to Source Voltage			20	V	
V _{GS}	Gate to Source Voltage			±12	V	
I _D	Drain Current -Continuous	T _A = 25 °C	(Note 1a)	9	٨	
	-Pulsed			40	— A	
P	Power Dissipation for Single Operation	T _A = 25 °C	(Note 1a)	2.1	W	
P _D	Power Dissipation for Single Operation $T_A = 25 \text{ °C}$ (Note 1b)			0.7	v	
T _J , T _{STG}	Operating and Storage Junction Temperatu	ire Range		-55 to +150	°C	

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	70	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	190	C/vv

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
8T	FDME820NZT	MicroFET 1.6x1.6 Thin	7 "	8 mm	5000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	20			V
ΔΒV _{DSS} ΔΤ _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		20		mV/°C
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 16 V, V _{GS} = 0 V			1	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
On Chara	cteristics			•		•
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	0.5	0.8	1.0	V
$\Delta V_{GS(th)}$ ΔT_J	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-3		mV/°C
r _{DS(on)} Drain to Sou	Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A}$		14	18	mΩ
		V _{GS} = 2.5 V, I _D = 7.5 A		17	24	
		V _{GS} = 1.8 V, I _D = 7 A		26	32	
		$V_{GS} = 4.5 \text{ V}, I_D = 9 \text{ A}, T_J = 125 \text{ °C}$		19	24	
Dynamic	Characteristics			<u>.</u>	<u>.</u>	
C _{iss}	Input Capacitance			865		pF
C _{oss}	Output Capacitance	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		203		pF
C _{rss}	Reverse Transfer Capacitance			190		pF
R _g	Gate Resistance			1.0		Ω
	Characteristics					
t _{d(on)}	Turn-On Delay Time			9		ns
t _r	Rise Time	$V_{DD} = 10 \text{ V}, \text{ I}_{D} = 4 \text{ A}$		5		ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 4.5 \text{ V}, \text{ R}_{GEN} = 2 \Omega$		19		ns
t _f	Fall Time			5		ns
Q _g	Total Gate Charge	$V_{DD} = 4.2 \text{ V}, I_D = 3 \text{ A}, V_{GS} = 4.3 \text{ V}$		8.0		nC
Q _g	Total Gate Charge	$V_{DD} = 4.2 \text{ V}, I_D = 3 \text{ A}, V_{GS} = 4.5 \text{ V}$		8.5		nC
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Drain-Source Diode Characteristics

Gate to Source Gate Charge

Gate to Drain "Miller" Charge

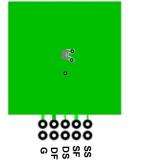
V	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 1.6 A$	(Note 2)	0.7	1.2	V
V _{SD} Source to Drain Diode Forward Voltage		V _{GS} = 0 V, I _S = 9 A	(Note 2)	0.8	1.2	V
t _{rr}	Reverse Recovery Time	IF = 9 A, di/dt = 100 A/us		18		ns
Q _{rr}	Reverse Recovery Charge			4		nC

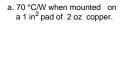
 $V_{DD} = 10 \text{ V}, \text{ I}_{D} = 9 \text{ A}$

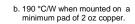
 Q_gs

 Q_{gd}

Notes: 1. R_{0,D4} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0,JC} is guaranteed by design while R_{0CA} is determined by the user's board design.







1.4

3.2

2. Pulse Test: Pulse Width < 300µs, Duty cycle < 2.0%. 3. The diode connected between the gate and source serves only as protection ESD. No gate overvoltage rating is implied.

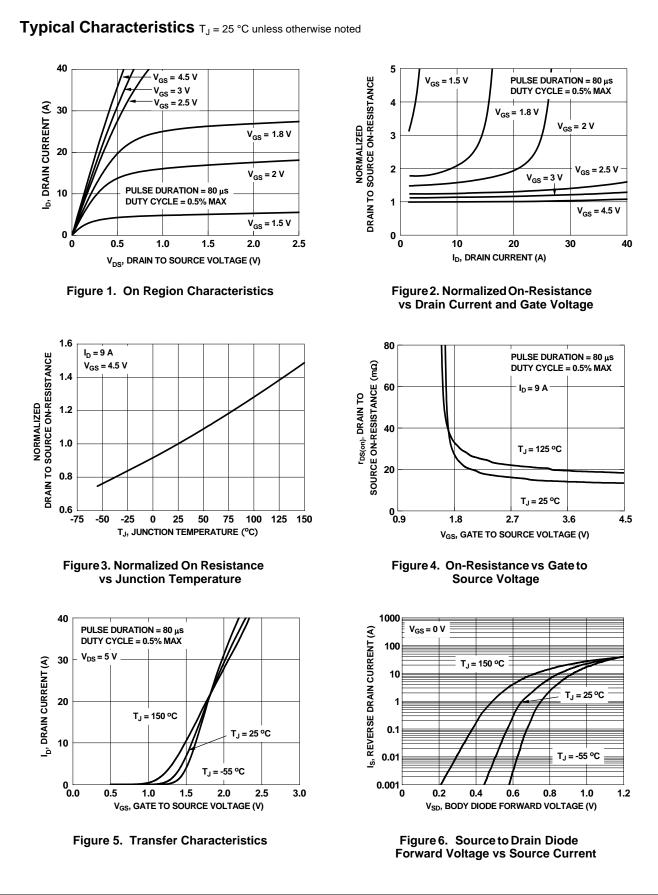
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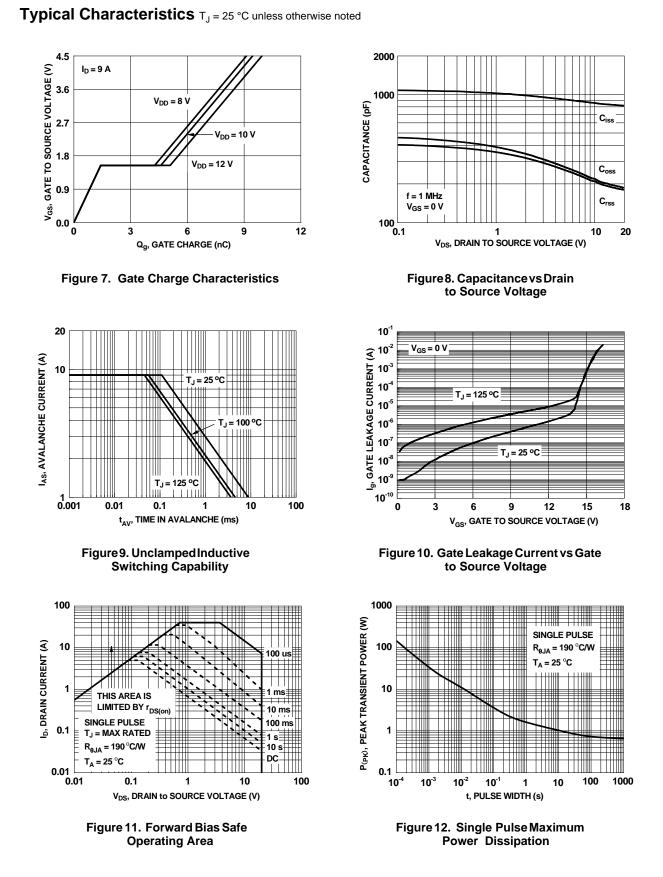
nC

nC

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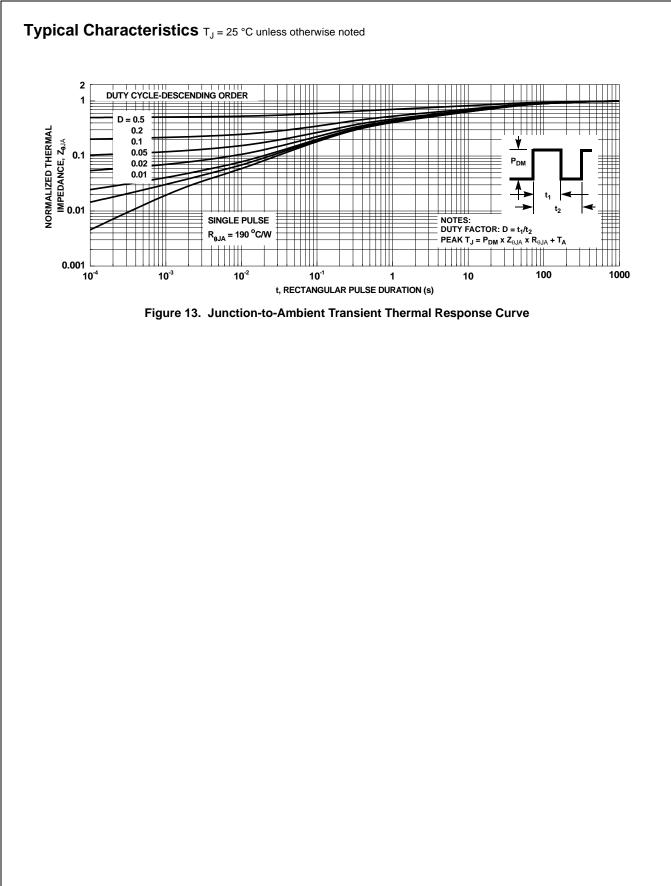


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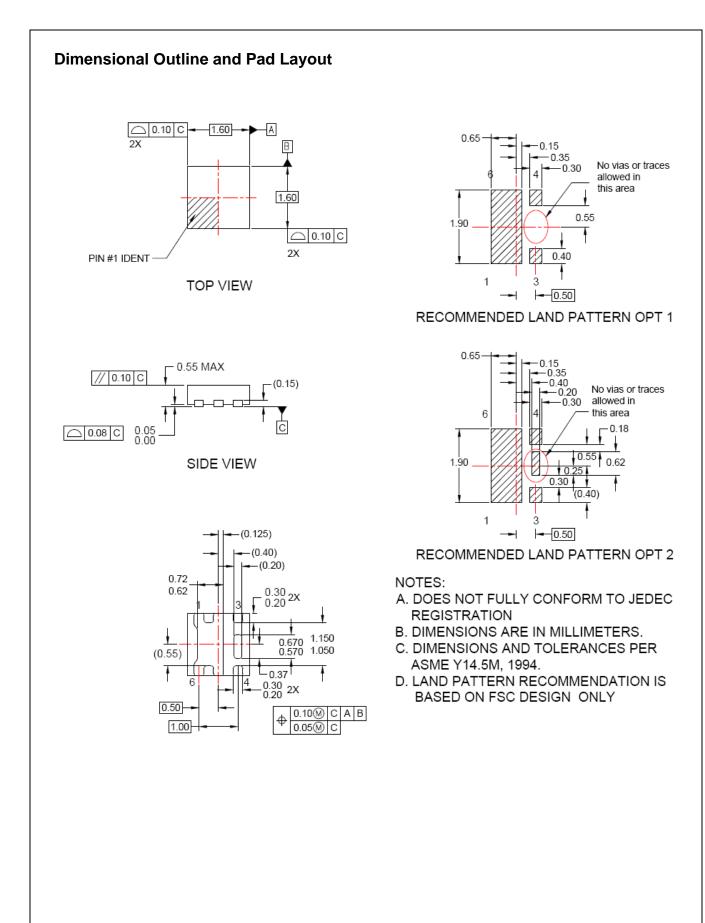


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